

## Features

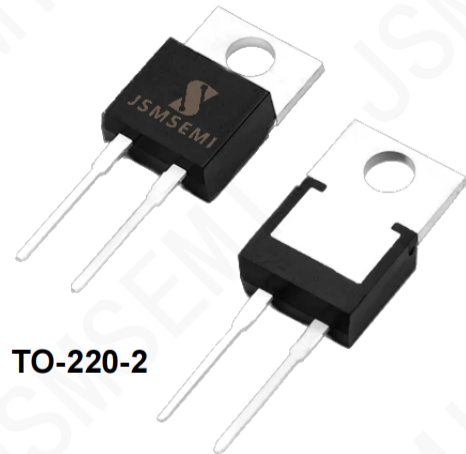
- Zero Forward/Reverse Recovery
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on  $V_F$
- Temperature Independent Switching Behavior
- 100% avalanche tested

## Benefits

- High System Efficiency
- Parallel Device Convenience
- High Temperature Application
- High Frequency Operation
- Hard Switching & High Reliability
- Environmental Protection

## Applications

- Switch Mode Power Supplies
- Solar Inverters
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies


**TO-220-2**


## Maximum Ratings ( $T_C=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$		650	V
Peak Reverse Surge Voltage	$V_{RSM}$		650	V
DC Blocking Voltage	$V_R$		650	V
Continuous Forward Current	$I_F$	$T_C=25^\circ\text{C}$ $T_C=135^\circ\text{C}$ $T_C=150^\circ\text{C}$	19 8 6	A
Non repetitive Forward Surge Current	$I_{FSM}$	$T_C = 25^\circ\text{C}$ , $t_p=10$ ms, Half Sine Pulse $T_C = 110^\circ\text{C}$ , $t_p=10$ ms, Half Sine Pulse $T_C = 25^\circ\text{C}$ , $t_p=10$ $\mu\text{s}$ , Square	40 35 300	A
Repetitive peak Forward Surge Current	$I_{FRM}$	$T_C = 25^\circ\text{C}$ , $t_p=10$ ms, Freq = 0.1Hz, 100 cycles, Half Sine Pulse $T_C = 110^\circ\text{C}$ , $t_p=10$ ms, Freq = 0.1Hz, 100 cycles, Half Sine Pulse	35 30	A
Total power dissipation	$P_D$	$T_C=25^\circ\text{C}$	68	W
Operating Junction Temperature	$T_J$		-55 to 175	$^\circ\text{C}$
Storage Temperature	$T_{STG}$		-55 to 175	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**Electrical Characteristics**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC Blocking Voltage	$V_{DC}$	$I_R = 250\mu A, T_J = 25^\circ C$	650			V
Forward Voltage	$V_F$	$I_F = 6A, T_J = 25^\circ C$		1.45	1.8	V
		$I_F = 6A, T_J = 125^\circ C$		1.6		
		$I_F = 6A, T_J = 175^\circ C$		1.75		
Reverse Current	$I_R$	$V_R = 650V, T_J = 25^\circ C$		7	80	$\mu A$
		$V_R = 650V, T_J = 125^\circ C$		38		
		$V_R = 650V, T_J = 175^\circ C$		108		
Total Capacitive Charge	$Q_C$	$V_R = 400V$		15		nC
Total Capacitance	C	$V_R = 1V, T_J = 25^\circ C,$ Freq = 1MHz		230		pF
		$V_R = 200V, T_J = 25^\circ C,$ Freq = 1MHz		33		
		$V_R = 400V, T_J = 25^\circ C,$ Freq = 1MHz		24		

**Thermal Characteristics**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance	$R_{th(j-c)}$	junction-case		1.8		$^\circ C/W$

**Ordering Information**

Order number	Package	Marking	Operation Temperature Range	MSL Grade	Ship,Quantity	Green
SIDH04SG60CXKSA2	TO-220-2	S6D06065A	-55 to 175 $^\circ C$	1	TUBE,1000	RoHS

Typical Electrical Curves

Figure 1. Forward Characteristics

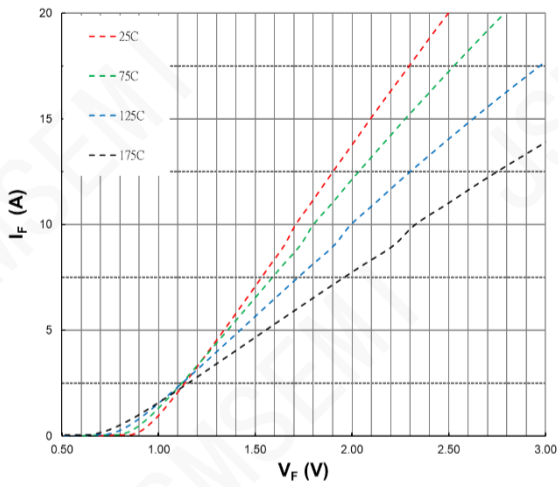


Figure 2. Forward Characteristics

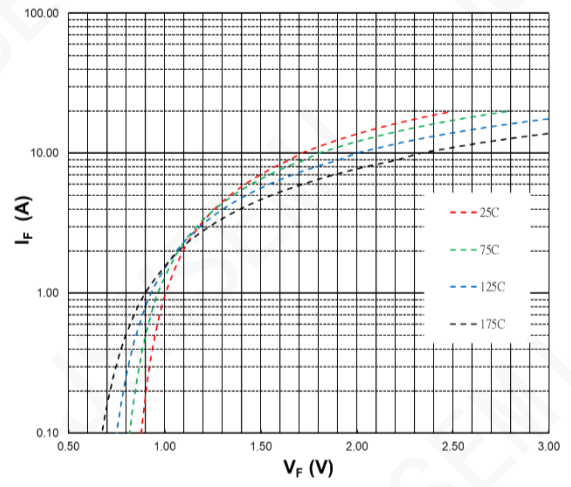


Figure 3. Reverse Characteristics

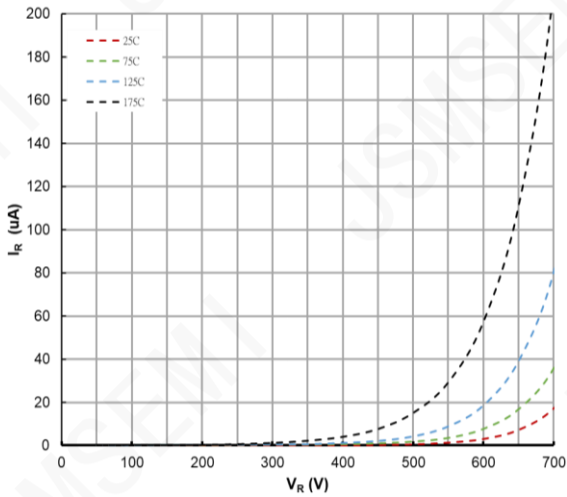


Figure 4. Power Derating

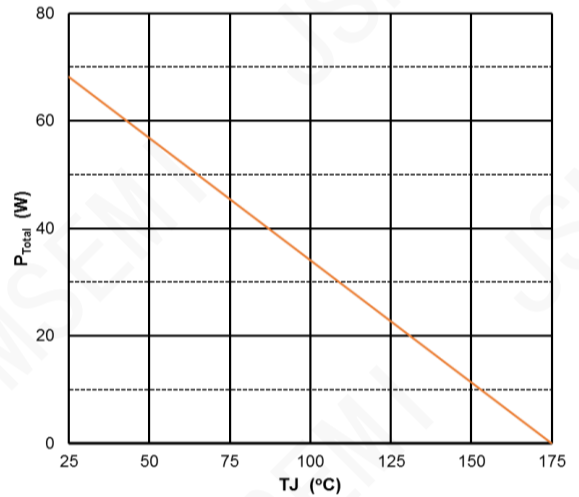


Figure 5. Capacitance vs Reverse Voltage

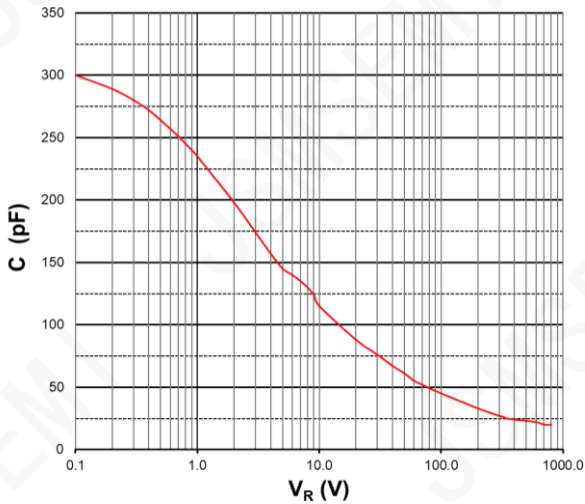
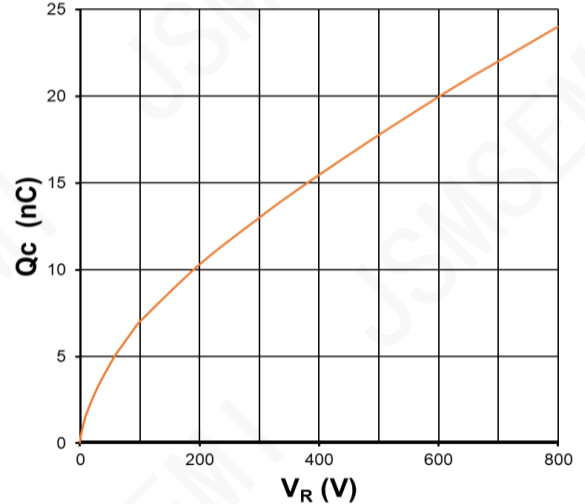
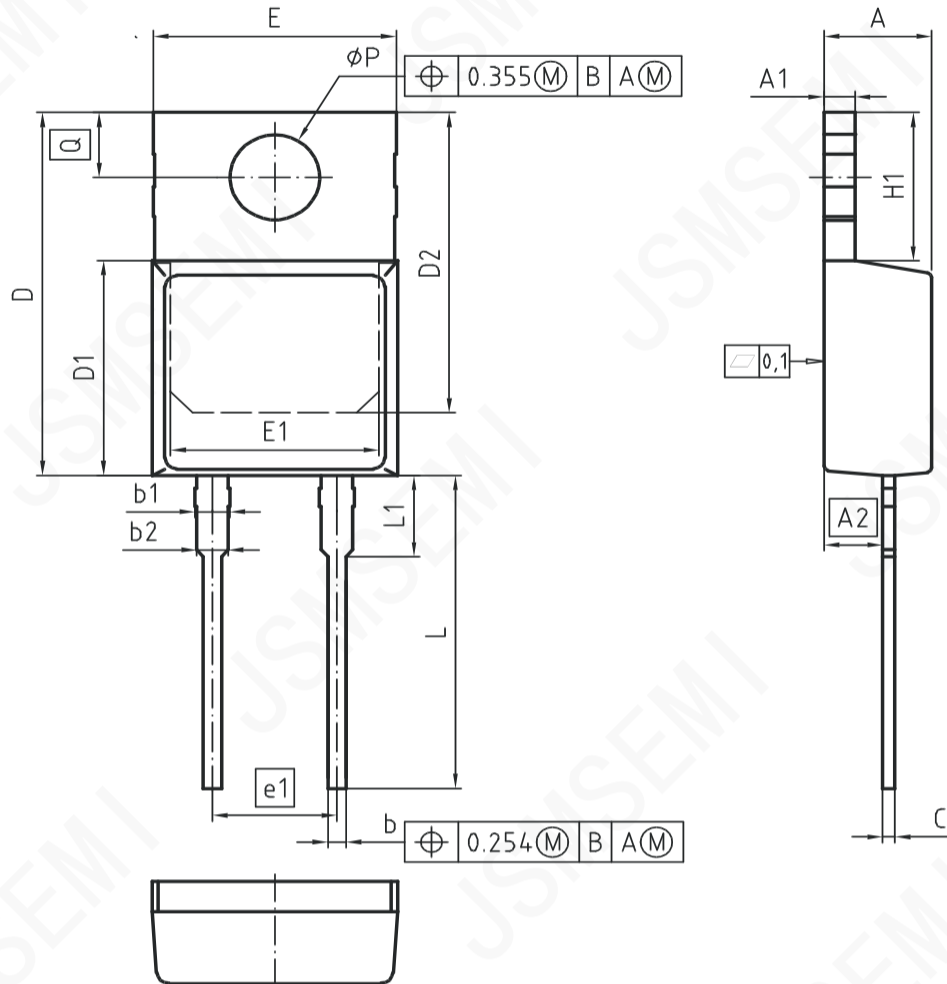


Figure 6. Recovery Charge vs Reverse Voltage



### Package Dimensions

(TO-220-2 Package)



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.50	0.169	0.177
A1	1.17	1.37	0.046	0.054
A2	2.30	2.50	0.091	0.098
b	0.65	0.85	0.026	0.033
b1	1.19	1.69	0.047	0.066
b2	1.19	1.39	0.047	0.055
c	0.40	0.60	0.016	0.024
D	15.35	15.95	0.604	0.628
D1	9.05	9.45	0.356	0.372
D2	12.30	13.05	0.484	0.514
E	9.80	10.20	0.386	0.402
E1	7.25	8.60	0.285	0.339
e1	5.08		0.200	
N	2		2	
H1	5.90	6.90	0.232	0.272
L	13.00	14.00	0.512	0.551
L1	3.30	3.70	0.130	0.146
$\phi P$	3.55	3.90	0.140	0.146
Q	2.60	3.00	0.102	0.118

## Revision History

Rev.	Change	Date
V1.0	Initial version	2/23/2022

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